# RENESAS

# **M61041FP** 4-Battery Version, No Reset Pin

REJ03F0063-0100Z Rev.1.0 Sep.19.2003

This product is currently under development, and its specifications, pin assignments, etc., are subject to change.

# Description

The M61041FP is an semiconductor IC device developed for smart battery packs. It incorporates all the analog circuitry required by smart batteries in a single chip. When used in conjunction with a microprocessor, it allows the implementation of a variety of functions, such as battery capacity detection, through the addition of minimal peripheral devices and is ideal for smart battery system (SBS) battery packs.

The M61041FP also has an on-chip overcurrent detect circuit so that the FET for controlling battery charging and discharging is protected regardless of the processing speed of the microprocessor.

The microprocessor can change the amplifier gain of the charge/discharge current detect circuit, so battery capacity detection accuracy is increased. In addition, the M61041FP incorporates a linear regulator that allows it to function as the power supply for the microprocessor, thereby simplifying power supply block design.

# Features

- On-chip high-gain op-amp for monitoring charge and discharge current.
- On-chip overcurrent detect circuit to protect FET.
- Charge/discharge FET can be controlled from microprocessor.
- Power-save function for reducing current consumption.
- 5.2 V operation to reduce microprocessor current consumption.
- High-voltage device (absolute maximum rating: 33 V).

# Application

• Smart battery system (SBS) battery packs

This product is currently under development, and its specifications, pin assignments, etc., are subject to change.

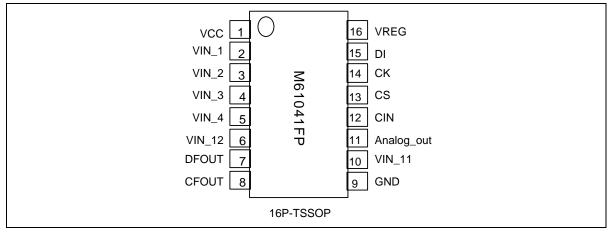


Figure 1 Pin Connection Diagram (Top View)



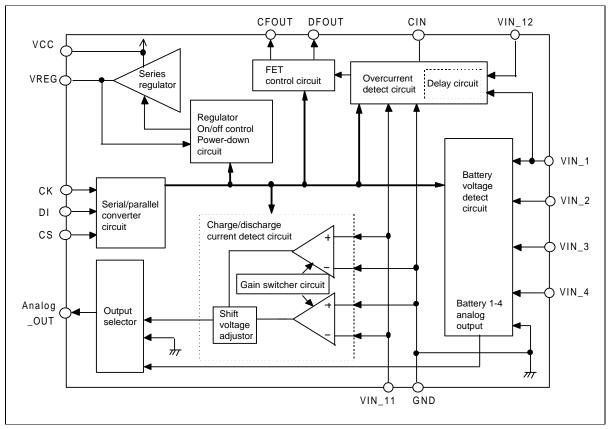


Figure 2 Block Diagram

# **Pin Function Description**

Table 1

Pin No.	Symbol	Function
1	Vcc	The chip's power supply pin. Power is supplied by the charger or the battery.
2	VIN_1	Positive input pin for lithium ion battery 1.
3	VIN_2	Negative input pin for lithium ion battery 1. Positive input pin for lithium ion battery 2.
4	VIN_3	Negative input pin for lithium ion battery 2. Positive input pin for lithium ion battery 3.
5	VIN_4	Negative input pin for lithium ion battery 3. Positive input pin for lithium ion battery 4.
6	VIN_12	Charger connect monitor pin. Detects changes from power-down status.
7	DFOUT	Output pin for discharge FET on/off signals. Also turns off when overcurrent detected.
8	CFOUT	Output pin for charge FET on/off signals.
9	GND	Ground pin. Negative input pin for lithium ion battery 4. Connected to charge/discharge
		current sensor resistor.
10	VIN_11	Charge/discharge current monitor pin. Connected to charge/discharge current sensor
		resistor.
11	Analog_OUT	Output pin for analog signals.
12	CIN	Capacity connection pin for setting overcurrent prevention delay time.
13	CS	When this pin is low level, data input is accepted and data can be stored in a 6-bit shift
		register. At the rising edge from low to high the value in the 6-bit shift register is
		latched.
14	СК	Shift clock input pin. At the rising edge to high the input signal from the DI pin is input to
		the 6-bit shift register.
15	DI	Shift data input pin. Serial data with a data length of 6 bits may be input via this pin.
16	Vreg	Power supply pin for microprocessor. Power can be shut off using a signal from the
		microprocessor.



### Operation

The M61041FP is an semiconductor IC device developed for smart battery packs. It is ideal for smart battery system (SBS) battery packs that consist of four lithium ion batteries connected in series. A high-voltage device, it is suitable for use with a wide variety of charger systems.

It incorporates all the analog circuitry required by smart batteries in a single chip. When used in conjunction with a microprocessor, it allows the implementation of a variety of functions, such as battery capacity detection, through the addition of minimal peripheral devices. The functions of the M61041FP are described below.

#### 1. Battery Voltage Detect Circuit

The M61041FP can output the voltage levels of the batteries connected in series via the Analog\_out pin. An onchip buffer amplifier monitors the pin voltages of the batteries. Offset voltage correction using adjustment by the microprocessor is also supported. The M61041FP is configured to detect the battery voltage using a microprocessor driven using a power supply voltage of 5.2 V.

#### 2. Charge/Discharge Current Detect Circuit

SBS requires a function for monitoring the battery capacity. The M61041FP uses an on-chip amplifier to monitor battery capacity based on a drop in the voltage of an external sensor resistor. In this way, the charge/discharge current is converted into a voltage.

The voltage amplification ratio can be adjusted from the microprocessor. In addition, the current output shift voltage can be adjusted from the microprocessor, widening the allowable dynamic range of the A/D converter.

#### 3. Overcurrent Detect Circuit

The M61041FP has an on-chip overcurrent detect circuit. If an excessive current flows from the lithium ion batteries, the discharge control FET is shut off after a set delay time, halting discharge. This makes the battery pack safer. The delay time can be set using an external capacitor. It is possible to determine the overcurrent detect status by monitoring the CIN pin. The overcurrent detect circuit provides protection regardless of the processing speed of the microprocessor.

#### 4. Series Regulator

The M61041FP has an on-chip low-dropout series regulator. It can be used as the power supply for the microprocessor, thereby simplifying power supply block design.

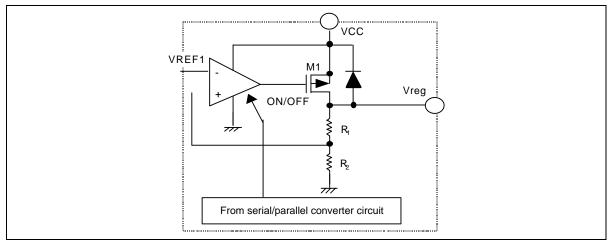


Figure 3 Series Regulator



5. Power-Save Function

The M61041FP is equipped with a power-save function.

When the battery voltage is being monitored a portion of the charge/discharge current monitor circuit automatically stops operating, and when the charge/discharge current is being monitored the battery voltage monitor circuit automatically stops operating. This helps prevent unnecessary power consumption. In addition, current consumption is further reduced by setting the analog output selector to ground potential output when in the standby mode.

#### Transition to Power-Down Mode

When the microprocessor determines that the battery voltage has dropped it sends a power-down instruction via the interface circuit. When it receives the instruction, the M61041FP's DFOUT pin switches to high voltage. In addition, the VIN\_12 pin is pulled down to low level by an internal resistor. When the VIN\_12 pin goes to low potential after reception of the power-down instruction, output from the series regulator stops, switching the M61041FP into power-down mode.

At this point the operation of the circuitry is completely halted. In this status CFOUT is high level and DFOUT is high level (external charge/discharge prohibited status). The maximum current consumption of the M61041FP is  $1.0 \mu$ A in order to prevent any further drop in the battery voltage.

#### **Cancellation of Power-Down Mode**

If the battery pack is connected to a charger when the M61041FP is in the power-down mode (VIN\_12 becomes high level), the series regulator immediately begins to operate. The power-down mode is canceled, and once again the M61041FP is ready to receive instructions from the microprocessor.

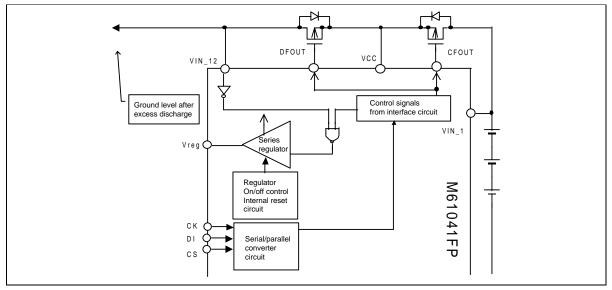


Figure 4 Operation After Excess Discharge Detection



# **Absolute Maximum Ratings**

Table 2

Item	Symbol	Rated Value	Unit	Conditions
Absolute maximum rating	Vabs	33	V	
Power supply voltage	Vcc	30	V	
Allowable loss	PD	500	mW	
Ambient operating temperature	Topr1	-20 to +85	°C	
Storage temperature	Tstg	-40 to +125	°C	

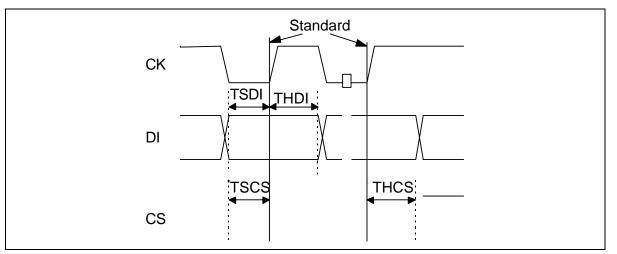


Figure 5 Interface Block Timing Definitions



# **Electrical Characteristics**

# Table 3

	Item		Rated Value						
Block		Symbol	Min.	Тур.	Max.	Unit	Circuit	Command	Conditions
All	Power supply voltage	Vsup	—	_	30	V	1	—	
	Circuit current	lsup1	60	150	215	μA	1	1	During charge/discharge current monitoring
	Circuit current 2	lsup2	55	140	200	μΑ	1	2	During battery voltage monitoring
	Circuit current 3	lsup3	25	80	115	μA	1	3	During ground output (initial status)
	Circuit current (power-down mode)	lpd	_	_	0.5	μΑ	1	4	All circuits halted, VIN_12 = GND
Regulator	Output voltage	Vreg	5.075	5.2	5.325	V	2	—	Vcc = 14V, lout = 20mA
	Input stability	$\Delta$ Vout10	_	60	100	mV	2	_	Vcc = $6.2V$ to $24V$ , lout = $20mA$
	Load stability	∆Vout20	—	30	50	mV	2	—	Vcc = 6.2V, lout = 0.1mA to 20mA
	Input voltage (VCC pin)	VIN0	6.2	_	30	V	2	—	
Overcurrent detect	Overcurrent prevention voltage 1	Vd1	0.18	0.2	0.22	V	3	5	
	Overcurrent prevention voltage 2	Vd2	Vcc/3×0.6	Vcc/3	Vcc/3×1.4	V	4	5	Load short detected
	Overcurrent prevention delay time 1	Tvd1	7	10	15	ms	3	5	CICT = 0.01µF
	Overcurrent prevention delay time 2	Tvd2	150	250	350	μs	4	5	
Battery voltage	Input offset voltage 1	Voff1	31	206	385	mV	5	6	
detect	Voltage amplification ratio 1	Gamp1	0.99	1.0	1.01		5	7	
	Output source current capacity	Isource1	150	_	_	μA	6	8	
	Output sink current capacity	lsink1	150	_	_	μA	6	9	
	Maximum detect battery voltage	Vmo_max	4.64	_	_	V	5	_	(Vreg–Voff1)/Gamp 1

 $(Ta = 25^{\circ}C, Vcc = 14 V \text{ unless otherwise specified})$ 

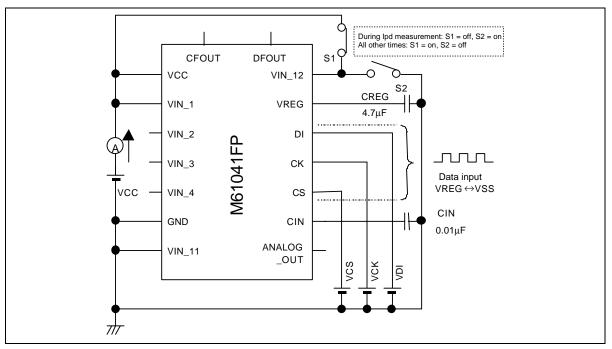
			Rated Value						
Block	Item	Symbol	Min.	Тур.	Max.	Unit	Circuit	Command	Conditions
Charge/ discharge	Input offset voltage	Voff2	1.0	2.4	3.8	V	7	10*	Gain = 200
current detect	Voltage amplification ratio 21	Gain21	38.4	40	41.6		7	11*	
	Voltage amplification ratio 22	Gain22	96	100	104		7	12*	
	Voltage amplification ratio 23	Gain23	192	200	208		7	13*	
	Current output shift voltage 1	Vios1	0.96	1.04	1.12	V	7	14*	
	Current output shift voltage 2	Vios2	1.93	2.08	2.23	V	7	15*	
	Current output shift voltage 3	Vios3	2.91	3.12	3.33	V	7	16*	
	Current output shift voltage 4	Vios4	3.49	3.74	3.99	V	7	17*	
	Output source current capacity	Isource2	150	_		μΑ	8	18*	
	Output sink current capacity	lsink2	150	—	_	μΑ	8	18*	
Interface	DI input H voltage	VDIH	Vreg-0.5	—	Vreg	V	9	—	
	DI input L voltage	VDIL	0	_	0.5	V	9	—	
	CS input H voltage	VCSH	Vreg-0.5	—	Vreg	V	9	_	
	CS input L voltage	VCSL	0	_	0.5	V	9	—	
	CK input H voltage	VCKH	Vreg-0.5	_	Vreg	V	9	_	
	CK input L voltage	VCKL	0	_	0.5	V	9	_	
	DI setup time	TSDI	600	—	_	ns	9	_	
	DI hold time	THDI	600	_	_	ns	9	—	
	CS setup time	TSCS	600		—	ns	9	—	
	CS hold time	THCS	600		—	ns	9	_	

Refer to figures 1 to 9 for the circuits and to table 4 for the command sequences used for measurement.

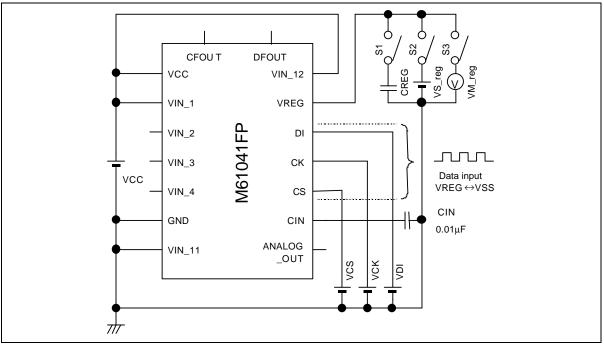
\* For the charge/discharge current detect block, different command sequences are used during charging and discharging.



# **Measurement Circuit Diagrams**

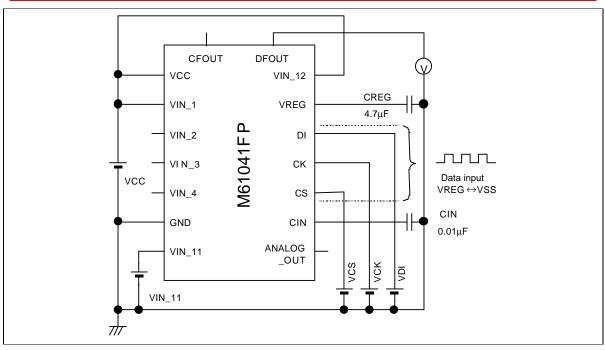


Circuit 1

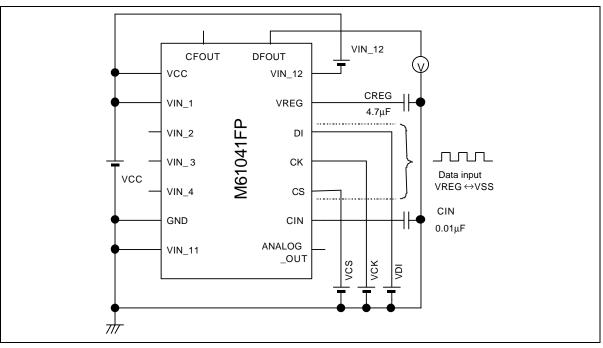


Circuit 2



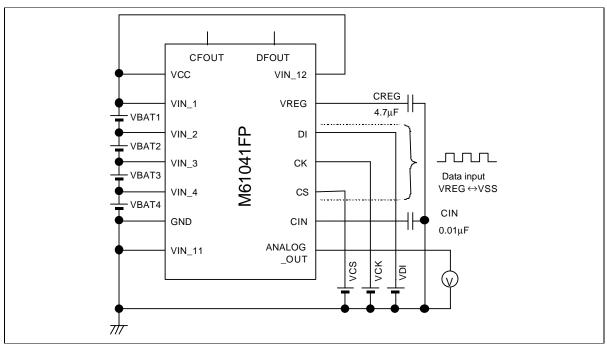


Circuit 3

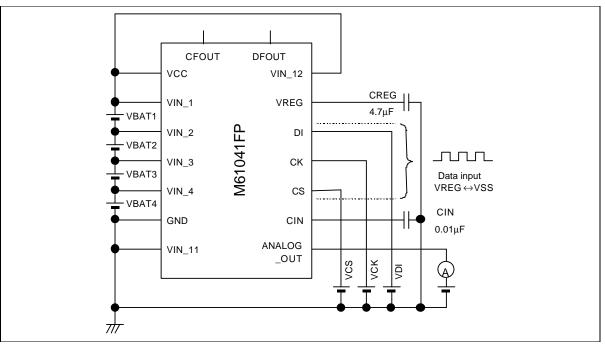


Circuit 4



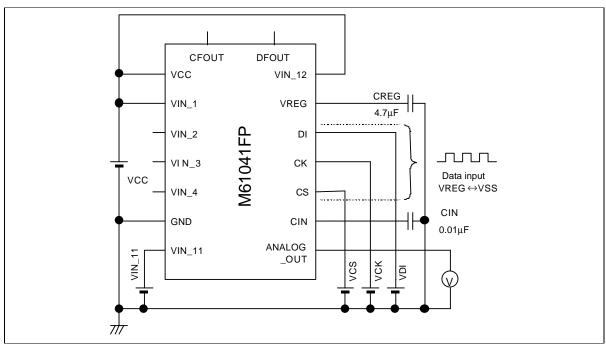




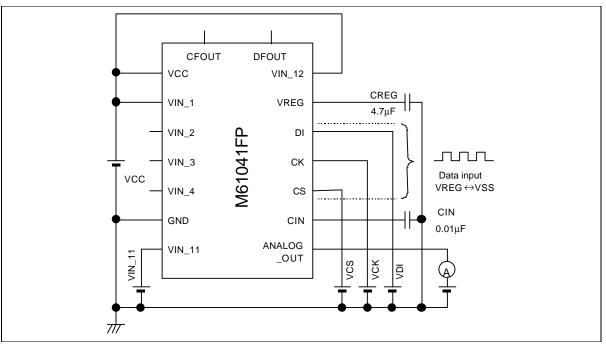


Circuit 6



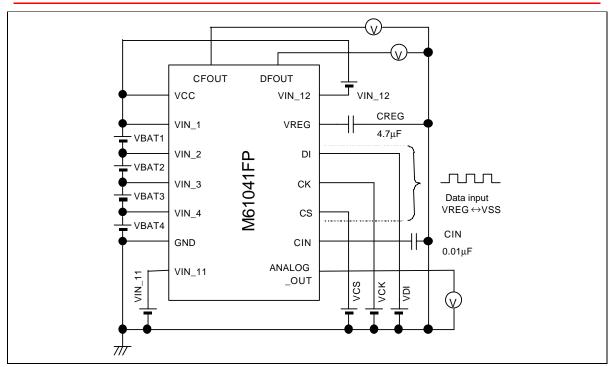






**Circuit 8** 





Circuit 9

No	Command Sequence	VIN_11 Input	
1	$(00)_{_8} \rightarrow (24)_{_8} \rightarrow (31)_{_8} \rightarrow (43)_{_8} \rightarrow (52)_{_8}$	90mV	
2	$(00)_{\scriptscriptstyle 8}  ightarrow (13)_{\scriptscriptstyle 8}  ightarrow (43)_{\scriptscriptstyle 8}  ightarrow (51)_{\scriptscriptstyle 8}$	0mV	
3	(00) <sub>8</sub>	0mV	
4	$(00)_{\scriptscriptstyle 8}  ightarrow (71)_{\scriptscriptstyle 8}$	0mV	
5	$(00)_{\scriptscriptstyle 8}  ightarrow (43)_{\scriptscriptstyle 8}$	0mV	
6	${(00)}_{_8} \rightarrow {(51)}_{_8} \rightarrow {(14)}_{_8} \rightarrow {(15)}_{_8} \rightarrow {(16)}_{_8} \rightarrow {(17)}_{_8}$	0mV	
7	$(00)_{_8} \rightarrow (51)_{_8} \rightarrow (10)_{_8} \rightarrow (11)_{_8} \rightarrow (12)_{_8} \rightarrow (13)_{_8}$	0mV	
8	${(00)}_{_8}  ightarrow {(51)}_{_8}  ightarrow {(13)}_{_8}$	0mV	
9	$(00)_{_8} \rightarrow (51)_{_8} \rightarrow (17)_{_8}$	0mV	
10	$(00)_{_8} \rightarrow (43)_{_8} \rightarrow (52)_{_8} \rightarrow (37)_{_8}$	0mV	
11	$(00)_{_8} \rightarrow (43)_{_8} \rightarrow (52)_{_8} \rightarrow (31)_{_8} \rightarrow (35)_{_8}$	90mV	
12	$(00)_{_8} \rightarrow (43)_{_8} \rightarrow (52)_{_8} \rightarrow (32)_{_8} \rightarrow (36)_{_8}$	25mV	
13	$(00)_{_8} \rightarrow (43)_{_8} \rightarrow (52)_{_8} \rightarrow (33)_{_8} \rightarrow (37)_{_8}$	3mV	
14	$(00)_{_8} \rightarrow (43)_{_8} \rightarrow (52)_{_8} \rightarrow (31)_{_8} \rightarrow (24)_{_8}$	90mV	
15	$(00)_{_8} \rightarrow (43)_{_8} \rightarrow (52)_{_8} \rightarrow (31)_{_8} \rightarrow (25)_{_8}$	90mV	
16	$(00)_{_8} \rightarrow (43)_{_8} \rightarrow (52)_{_8} \rightarrow (31)_{_8} \rightarrow (26)_{_8}$	90mV	
17	$(00)_{_8} \rightarrow (43)_{_8} \rightarrow (52)_{_8} \rightarrow (31)_{_8} \rightarrow (27)_{_8}$	90mV	
18	$(00)_{_8} \rightarrow (43)_{_8} \rightarrow (52)_{_8} \rightarrow (31)_{_8}$	45mV	

#### Table 4 Command Sequences Used for Measuring Rated Values

Notes : 1. Indications such as (00)<sub>8</sub> show the address and data, in that order, of the serial data from the microprocessor in octal notation.

2. Numbers 10 to 17 are command sequences used during charging. For the commands used during discharging, substitute (53)<sub>8</sub> for (52)<sub>8</sub>.

3. During measurement, the voltage listed in table 4 should be input to VIN\_11. When measuring during charging, the specified voltage should be input to VIN\_11 as a negative voltage. The specified voltage should be input to VIN\_11 as a positive voltage during discharging.



# **Description of Circuit Blocks**

(1) Battery Voltage Detect Circuit

As shown in figure 6, the battery voltage detect circuit block of the M61041FP consists of switches, a buffer amplifier, a reference voltage circuit, and a logic circuit.

When the voltage to be detected is selected, based on serial data from the microprocessor, the appropriate switch connections are determined by the logic circuit. The voltages Vbat1, Vbat2, Vbat3, and Vbat4 from the batteries connected to the M61041FP, multiplied by Gamp1 (1.0), are output from the Analog\_out pin. It is also possible to output an offset voltage.

In the power-save mode all the switches are turned off, so the current consumption of this circuit block is zero.

Note : The settling time of this circuit block after voltage changes is about 50 µs.

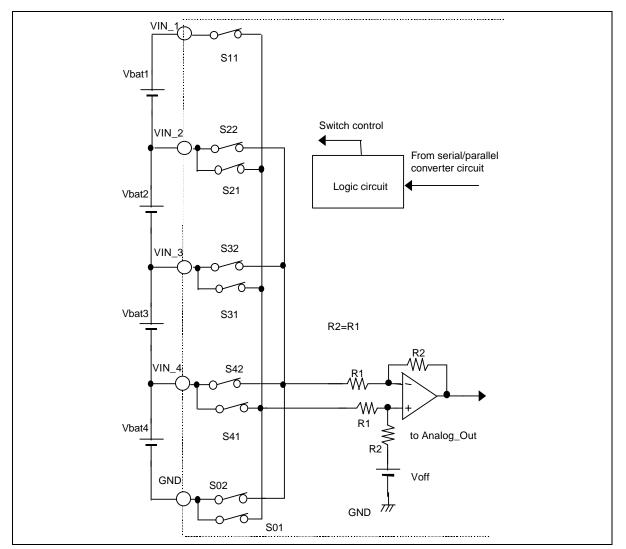


Figure 6 Battery Voltage Detect Circuit

#### Battery Voltage Monitoring Method

To select battery voltage detection, serial data  $(51)_8$  is sent from reset status  $(00)_8$ . The V1 battery voltage (Vin1) is output from the analog output pin by sending  $(10)_8$ . Next,  $(14)_8$  is sent to switch the analog output pin from the V1 battery voltage to the V1 offset voltage (Voff1). The actual voltage (Vbat1) can be obtained by the microprocessor by calculating <u>Vbat1 = (Vin1 - Voff1) / Gamp</u>. The same method can be used for Vbat2 to Vbat4 in order to monitor the battery voltage with a high degree of accuracy.

#### (2) Charge/Discharge Current Detect Block

As shown in figure 7, the charge/discharge current detect block of the M61041FP consists of a preamplifier current output shift voltage adjustment circuit, a buffer amplifier, and dividing resistors.

The voltage difference indicated by the sensor resistor is amplified to the ground reference voltage by the preamplifier. The gain can be switched using serial signals from the microprocessor. The output is impedance converted by the buffer amplifier.

It is also possible to switch the current detect shift voltage using the microprocessor.

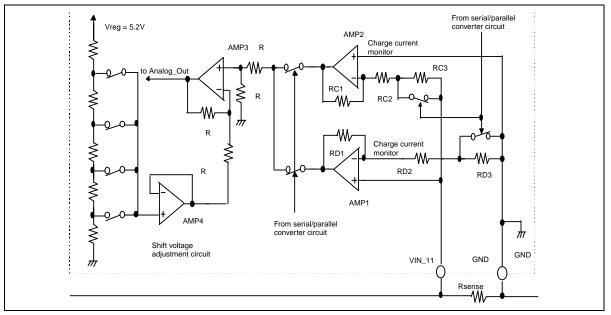


Figure 7 Charge/Discharge Current Detect Block

Figure 8 illustrates the circuit block's operation during discharge current detection. The discharge current flows into Rsense, and any voltage drop that occurs is applied to the positive terminal of the amplifier (AMP1). The amplifier's gain can be increased by an instruction from the microprocessor, making it possible to monitor even minute discharge currents with high accuracy.

To allow monitoring of the charge current, the voltage generated by VIN\_11 is inverted and amplified before being output. The other aspects use the same operating principle as that described above.



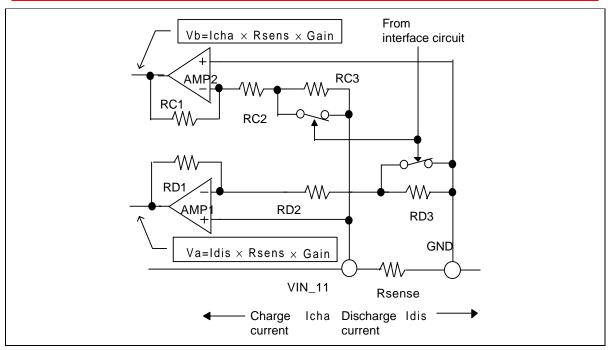


Figure 8 Charge/Discharge Current Detect Explanation Diagram

(3) Overcurrent Detect Circuit Block

As shown in figure 9, the overcurrent detect circuit block of the M61041FP consists of a comparator, a reference voltage circuit, and a delay circuit.

The detection voltage can be adjusted by trimming, making possible highly accurate voltage detection in conjunction with a sensor resistor. In addition, it is possible to determine when the M61041FP is in overcurrent detect status by monitoring the CIN pin using the microprocessor.

The M61041FP is also equipped with a simplified load detect circuit. Based on the status of the Vin12 pin it is possible to provide protection with a shorter delay time than when using overcurrent detection.

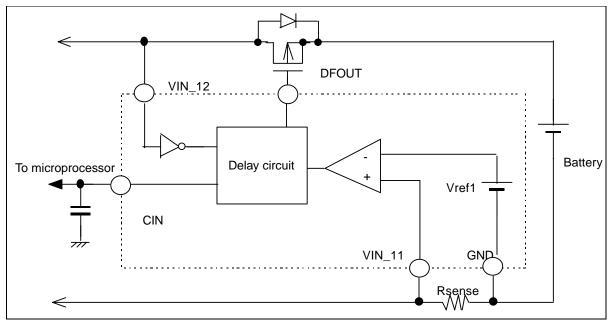


Figure 9 Overcurrent Detect Circuit Block



#### (4) Series Regulator

The series regulator circuit is shown in figure 10. A Pch MOS transistor is used as the output control transistor. The output voltage is adjusted by the M61041FP internally, so no external devices, such as resistors, are required.

Note : Due to the structure of the control transistor a parasite diode is formed between VCC and Vreg. This means that the M61041FP can be destroyed by reverse current if the Vreg potential exceeds VCC. Consequently, Vreg should be limited to VCC + 0.3 V or less.

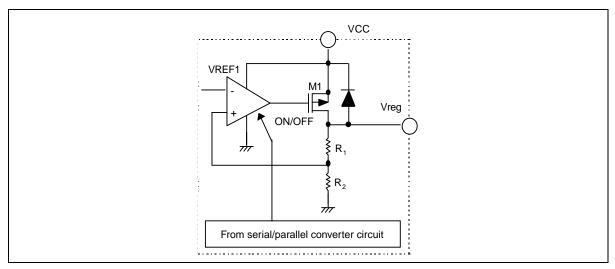


Figure 10 Series Regulator

#### **Digital Data Format**

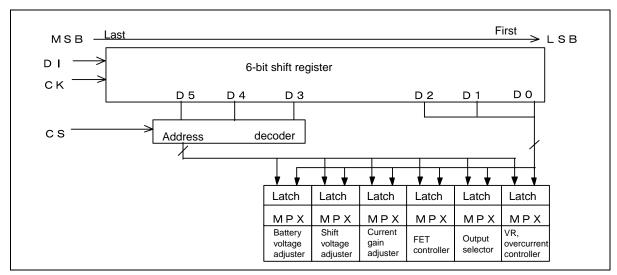


Figure 11 Serial/Parallel Converter Circuit Block Diagram

### Data Timing Diagram (Model)

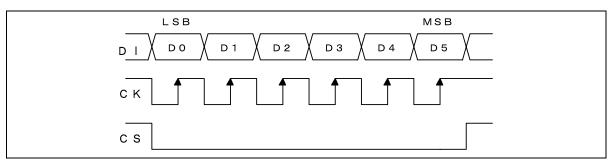


Figure 12 Serial/Parallel Converter Circuit Timing Chart

#### **Data Content**

Table 5

	Addre	SS	Data				
Setting Data	D5	D4	D3	D2	D1	D0	Content
Reset	0	0	0	_	_	_	
Battery voltage selector	0	0	1	_	_	_	See table 8
Current output shift voltage adjuster	0	1	0	_			See table 9
Current monitor gain adjuster	0	1	1	_			See table 10
FET controller	1	0	0	_	_	_	See table 11
Output selector	1	0	1				See table 12
Regulator	1	1	1	_			See table 13
Overcurrent detection controller							

### **Data Content**

## Table 6 Battery Voltage Selector

D5 to D3	D2	D1	D0	Output Voltage	Note
001	0	0	0	V1 voltage	Selected after reset
001	0	0	1	V2 voltage	
001	0	1	0	V3 voltage	
001	0	1	1	V4 voltage	
001	1	0	0	V1 offset voltage	
001	1	0	1	V2 offset voltage	
001	1	1	0	V3 offset voltage	
001	1	1	1	V4 offset voltage	

• V1 voltage is selected after reset.

# Table 7 Current Output Shift Voltage Adjuster

D5 to D3	D2	D1	D0	Current Output Shift Voltage Value	Note	
010	0	0	0	0 V (no shift voltage)	Selected after reset	
010	0	0	1	0 V (no shift voltage)		
010	0	1	0	0 V (no shift voltage)		
010	0	1	1	0 V (no shift voltage)		
010	1	0	0	1V	Vreg/25×5	
010	1	0	1	2V Vreg/25×10		
010	1	1	0	3V Vreg/25×15		
010	1	1	1	3.6V Vreg/25×18		

• No current output shift voltage after reset.



D5 to D3	D2	D1	D0	Output Gain Switch	Note	
011	0	0	0	Amplifier off	Selected after reset	
011	0	0	1	40x (current value output)		
011	0	1	0	100× (current value output)		
011	0	1	1	200× (current value output)		
011	1	0	0	Amplifier off	Same as after reset	
011	1	0	1	40x (offset output)		
011	1	1	0	100× (offset output)		
011	1	1	1	200× (offset output)		

### Table 8 Charge/Discharge Current Detector

• Amplifier off after reset.

### **Table 9 FET Controller**

D5 to D3	D2	D1	D0	CFOUT	DFOUT	Note
100	0	0	0	High	High	Selected after reset
100	0	0	1	Low	High	
100	0	1	0	High	Low	
100	0	1	1	Low	Low	
100	1	0	0	Don't care	Don't care	
100	1	0	1	Don't care	Don't care	
100	1	1	0	Don't care	Don't care	
100	1	1	1	Don't care	Don't care	

• DFOUT and CFOUT pins set to off after reset. (Current control FET is off when output is high level.)

# Table 10 Output Selector

D5 to D3	D2	D1	D0	Output Selection	Note	
101	0	0	0	Ground output	Selected after reset	
101	0	0	1	Battery voltage value output		
101	0	1	0	Charge current value output		
101	0	1	1	Discharge current value output		
101	1	0	0	Don't care		
101	1	0	1	Don't care		
101	1	1	0	Don't care		
101	1	1	1	Don't care		

• Ground potential output after reset.

### Table 11 Regulator, Overcurrent Detection Controller

D5 to D3	D2	D1	D0	Voltage Regulator Output	<b>Overcurrent Detect Circuit</b>	Note
111	0	0	0	ON	ON	Selected after reset
111	0	0	1	OFF	OFF	Both circuits off
111	0	1	0	ON	CIN pin fixed low	Overcurrent circuit off
111	0	1	1	ON	CIN pin fixed high	Overcurrent circuit off
111	1	0	0	Don't care	Don't care	
111	1	0	1	Don't care	Don't care	
111	1	1	0	Don't care	Don't care	
111	1	1	1	Don't care	Don't care	

• Regulator output and overcurrent circuit both on after reset.

Note: A setting of 111001 caused the M61041FP to transition to the power-down mode. However, transition to the power-down mode does not occur when connected to a charger (VIN\_12 is high level).



# **Timing Charts**

### **Charging Sequence**

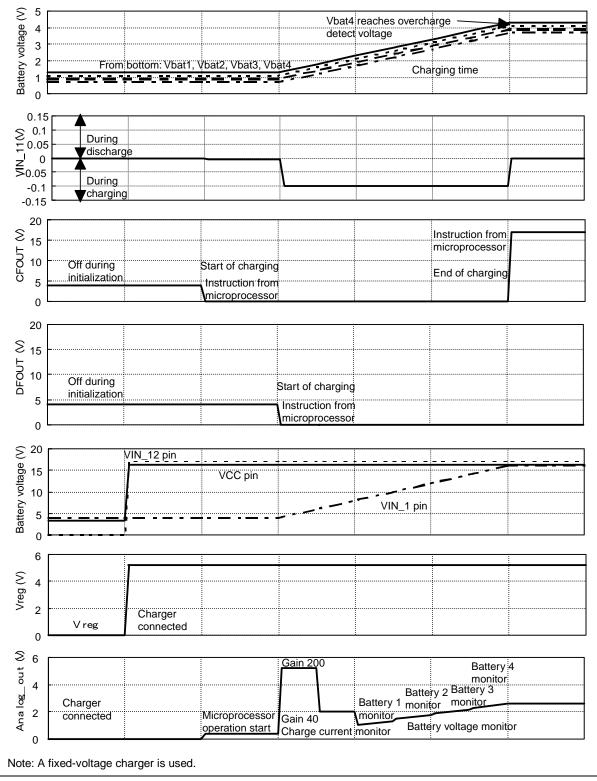
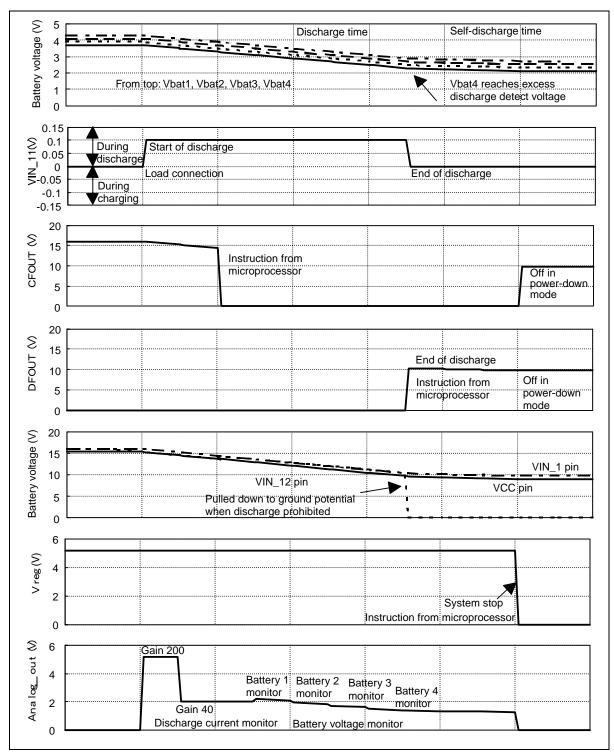


Figure 13 Charging Sequence

**Discharge Sequence** 



**Figure 14 Discharge Sequence** 

# **Overcurrent Sequence**

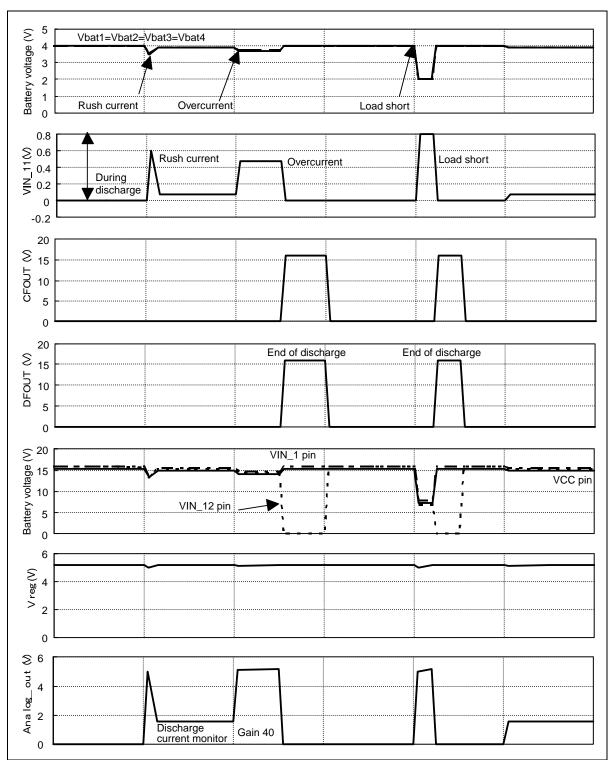
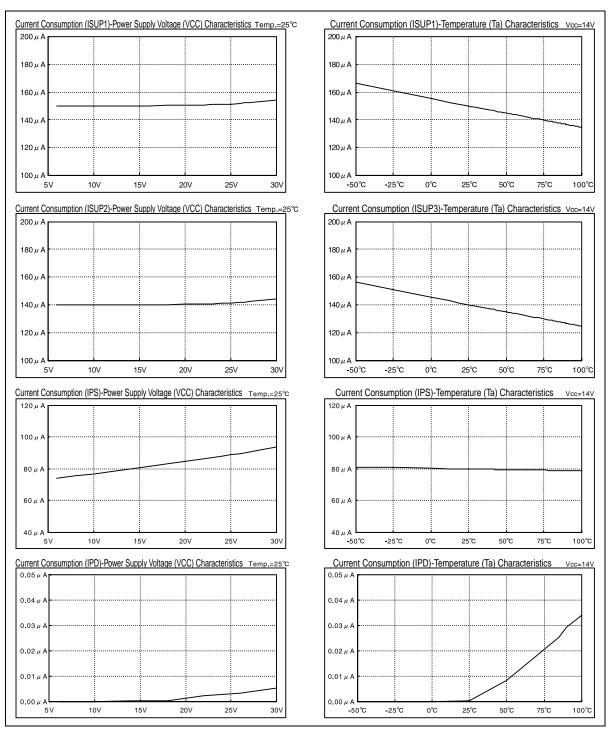


Figure 15 Overcurrent Sequence



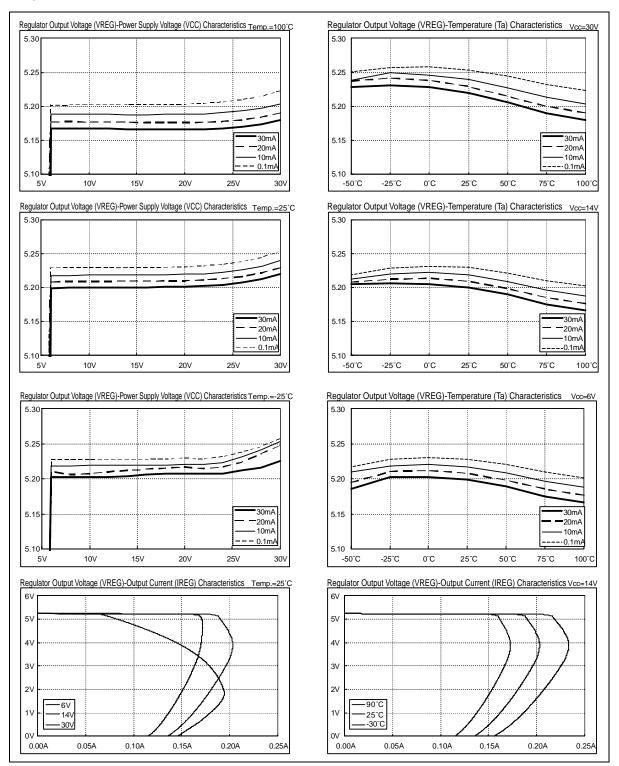
#### **Principal Item Characteristics**

Overall



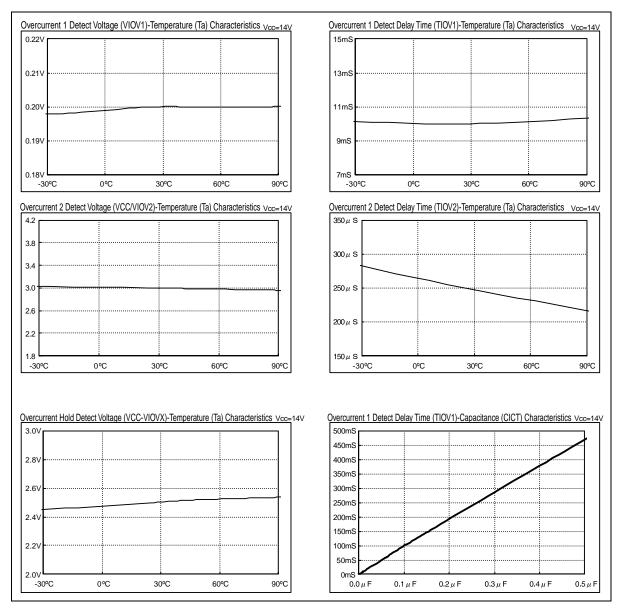


#### Regulator Block





#### Overcurrent Detect Block





## Battery Voltage Detect Block

0.40V		1.00%	 
.35V	 	0.75%	 
		0.50%	 
.30V	 	0.25%	 
.25V <del></del>	 	0.00%	
.20V		-0.25%	 
	V1_offset V2_offset	-0.50%	 V1_Gain_err
.15V	 V3_offset	-0.75%	 V3_Gain_er
.10V	 V4_offset	-1.00%	V4_Gain_er

Discharge XXXXX

8mV					18mV				
6mV					16mV				
4mV					14mV				
2mV					12mV				
					10mV				
0mV				iset 40					ffset 40
8mV				iset100 - iset200	8mV				ffset100- ffset200
	:	i			6mV				
6mV <b>-</b>	0°C	30°C	60°C	90°C	-30°C	0°C	30°C	6ºC	90°C
-30°C tery Voltage Amp			60°C re (Ta) Characterist		-30°C Discharge Current A				
-30°C tery Voltage Amp 4%					Discharge Current A				
-30°C tery Voltage Amp 4%					Discharge Current A				
-30°C tery Voltage Amp 4%					Discharge Current A				
-30°C tery Voltage Amp 4% 3% 2%					Discharge Current A				
-30°C tery Voltage Amp 4% 2% 1% 0%					Discharge Current A				
-30°C tery Voltage Amp 4% 2% 1%			re (Ta) Characterist	<u>tics vreg=</u> 5.2V	Discharge Current A			iture (Ta) Characte	ristics vreg=5.
			re (Ta) Characterist		Discharge Current A			ture (Ta) Characte	



# **Sample Application Circuit**

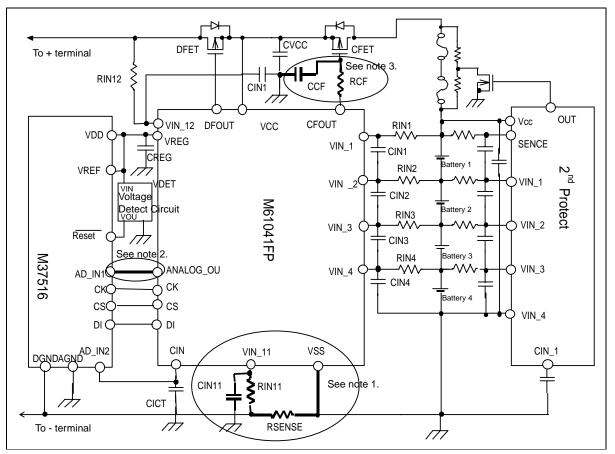


Figure 16 Sample Application Circuit

### Notes on Circuit Board Design

- The current sensor resistor (RSENSE) should be located adjacent to the VSS and VIN\_11 pins of the M61041FP. In addition, no circuitry other than that recommended above should be added between the M61041FP and RSENSE. Any extraneous current flow in this channel could result in errors when measuring the charge and discharge currents.
- 2. The load capacitance of the ANALOG\_OUT pin, including parasite capacitance, should be no more than 10 pF. If a capacitor of more than 10 pF is connected, the output from ANALOG\_OUT may begin to oscillate.
- 3. Power supply fluctuations during overcurrent detection and when connected to a charger may cause the M61041FP to reset. It is possible to prevent incorrect operation by connecting a CR filter to the control signal of the charge control FET.



### Table 12 External Device Constants

Device	Symbol	Purpose	Recommen ded Value	Min.	Max.	Notes	
Pch MOSFET	DFET	Discharge control	_	_	_	_	
Pch MOSFET	CFET	Charge control	_	_	_		
Resistor	RIN1	ESD countermeasure	10Ω	_	1kΩ	1) Values differ among RIN2 to RIN4.	
Capacitor	CIN1	Power supply	0.22µF	_	1.0µF		
		fluctuation	·				
		countermeasure					
Resistor	RIN2	ESD countermeasure	1kΩ	_	1MΩ	—	
Capacitor	CIN2	Power supply	0.22µF	_	1.0μF		
		fluctuation					
		countermeasure					
Resistor	RIN3	ESD countermeasure	1kΩ	_	1MΩ	2) RIN2 and CIN2 should be set to the	
Capacitor	CIN3	Power supply	0.22µF	—	1.0μF	same value.	
		fluctuation					
		countermeasure					
Resistor	RIN4	ESD countermeasure	1kΩ	_	1MΩ	2) RIN2 and CIN2 should be set to the	
Capacitor	CIN4	Power supply	0.22µF	—	1.0μF	same value.	
		fluctuation					
		countermeasure					
Resistor	RIN11	Power supply	100Ω		200Ω	3) The upper value for confirmation of	
		fluctuation				overcurrent operation should be adjusted	
		countermeasure				as necessary.	
Capacitor	CIN11	Power supply	0.1µF	_	1.0μF		
		fluctuation					
Desister	DINIAO	countermeasure	101-0	2000	10040	2) The upper value for confirmation of	
Resistor	RIN12	Charger reverse connection	10kΩ	300Ω	100kΩ	<ol> <li>The upper value for confirmation of overcurrent operation should be adjusted</li> </ol>	
		countermeasure				as necessary.	
Capacitor	CIN12	Power supply	0.01µF	_	0.1µF		
Capacitor	0	fluctuation	010 1µ1		011. μ.		
		countermeasure					
Capacitor	CVCC	Power supply	0.22µF	_	_		
·		fluctuation	·				
		countermeasure					
Sensor	RSENSE	Charge/discharge	$20 \text{m}\Omega$	_	_	—	
resistor		current monitoring					
Capacitor	CICT	Delay time setting	0.01µF	_	0.47μF		
Capacitor	CREG	Output voltage	4.7μF	0.47µF	—	—	
		fluctuation					
		countermeasure					
Resistor	RCF	Power supply	1kΩ	500Ω	—	3) The upper value for confirmation of	
		fluctuation				overcurrent operation should be adjuste	
		countermeasure				as necessary.	
Capacitor	CCF	Power supply	0.1µF	0.047μF	—		
		fluctuation					
		countermeasure					

# **Package Dimensions**

16P2X

Note: Please contact Renesas Technology Corporation for further details.



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